

# Device Modeling Report

COMPONENTS: Power MOSFET (Model Parameters)

PART NUMBER: 2SJ650

MANUFACTURER: SANYO

Body Diode (Model Parameters) / ESD Protection Diode

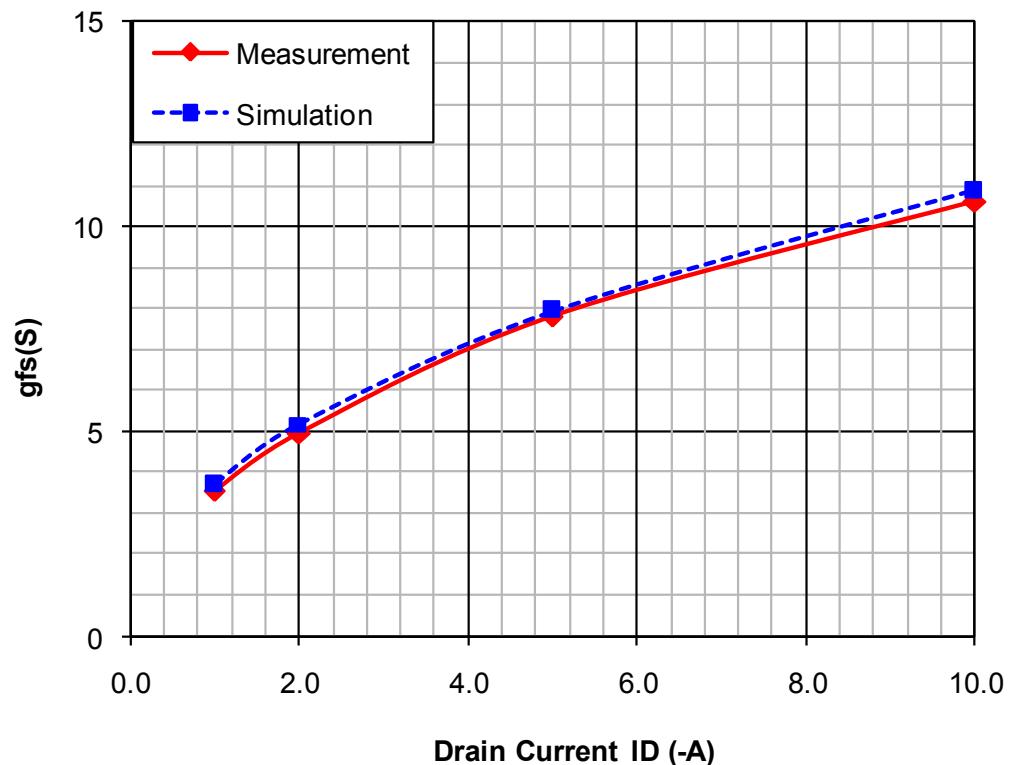


## MOSFET MODEL

<b>PSpice model parameter</b>	<b>Model description</b>
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Mobility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

## Transconductance Characteristic

Circuit Simulation Result

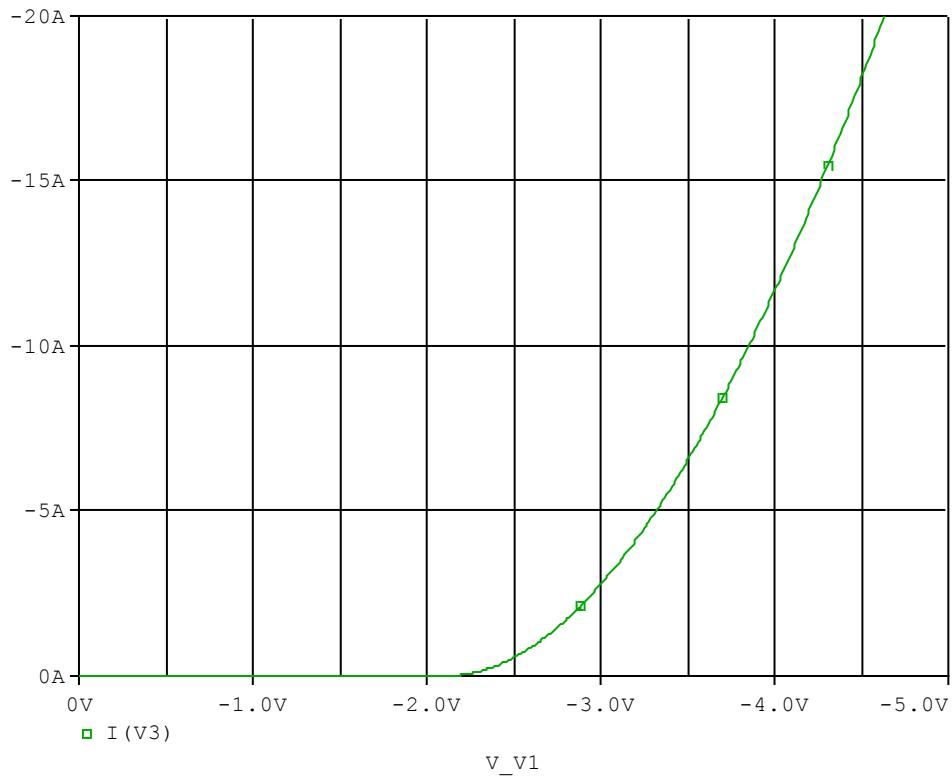


Comparison table

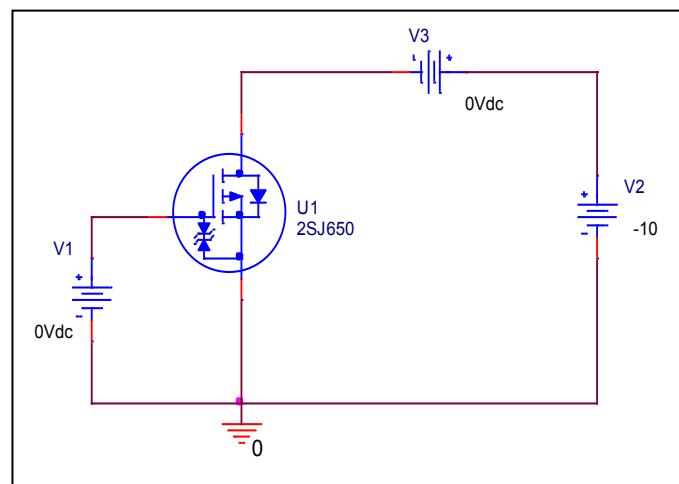
-Id(A)	gfs(S)		Error (%)
	Measurement	Simulation	
1.0000	3.550	3.707	4.42
2.0000	4.950	5.162	4.28
5.0000	7.800	7.928	1.64
10.0000	10.600	10.862	2.47

## V<sub>gs</sub>-I<sub>d</sub> Characteristic

Circuit Simulation result

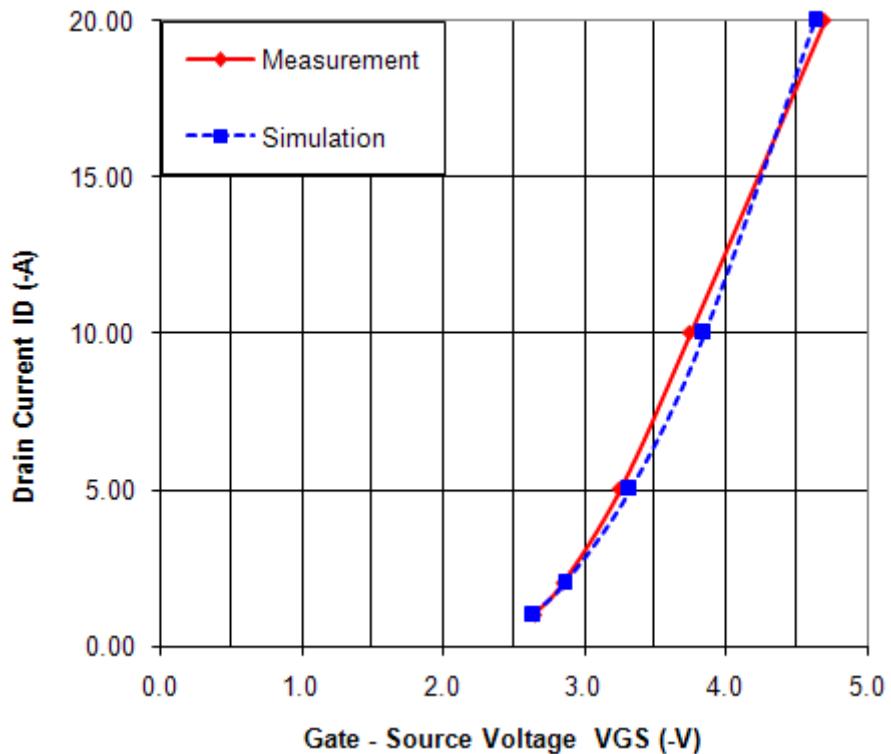


Evaluation circuit



## Comparison Graph

Circuit Simulation Result

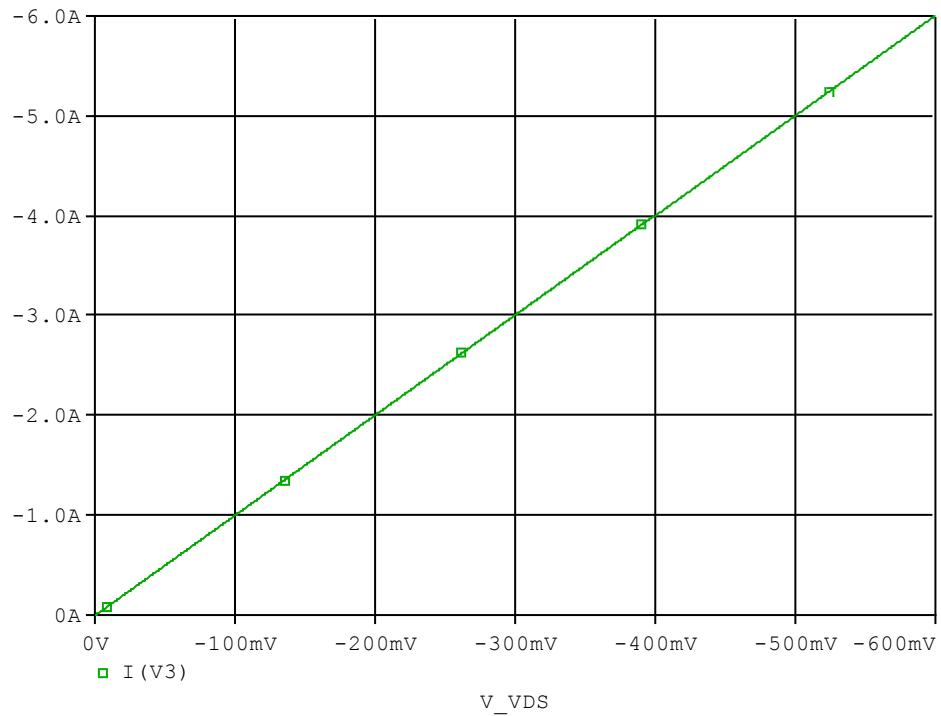


Simulation Result

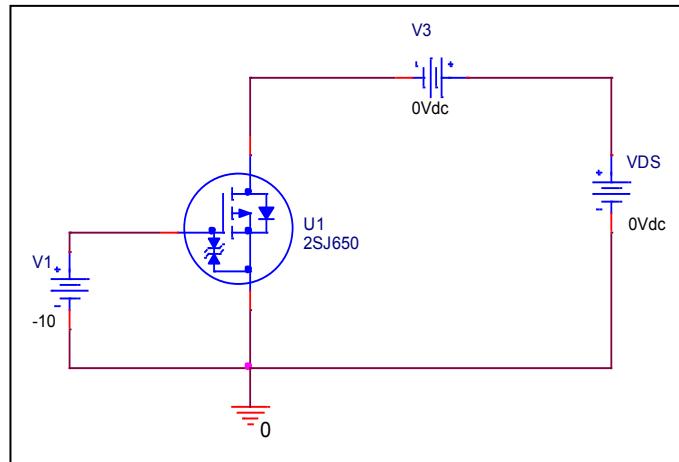
$-I_D$ (A)	$-V_{GS}$ (V)		Error (%)
	Measurement	Simulation	
1	2.650	2.638	-0.47
2	2.850	2.863	0.45
5	3.250	3.320	2.15
10	3.750	3.851	2.69
20	4.700	4.632	-1.46

## Rds(on) Characteristic

### Circuit Simulation result



### Evaluation circuit

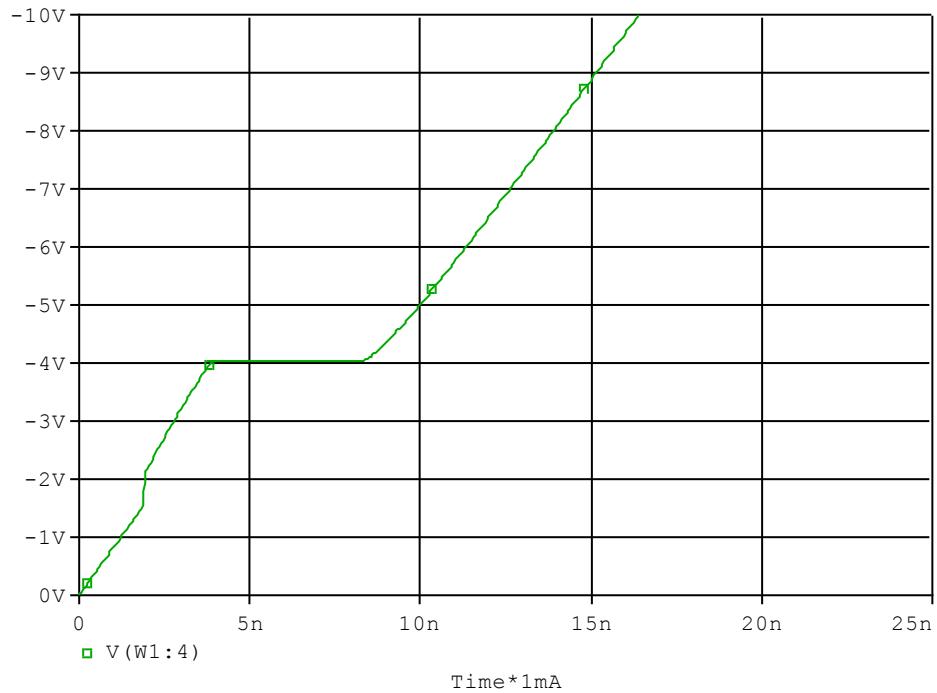


### Simulation Result

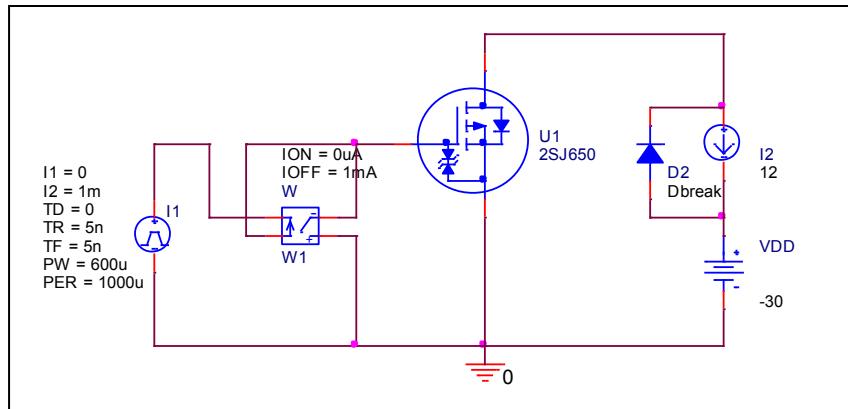
I <sub>D</sub> =-6A, V <sub>GS</sub> =-10V		Measurement	Simulation	Error (%)
R <sub>DS</sub> (on)	mΩ	100.000	100.000	0.00

## Gate Charge Characteristic

### Circuit Simulation result



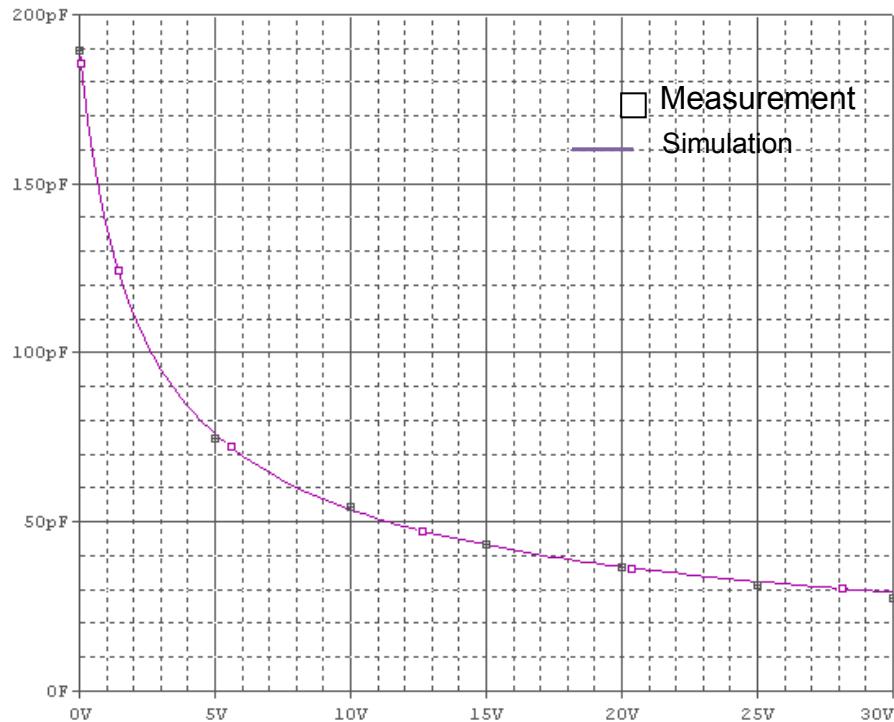
### Evaluation circuit



### Simulation Result

$V_{DD}=-30V, I_D=-12A, V_{GS}=-10V$		Measurement	Simulation	Error (%)
Qgs	nC	3.800	3.868	1.79
Qgd	nC	4.500	4.480	-0.45
Qg	nC	21.000	16.400	-21.90

## Capacitance Characteristic

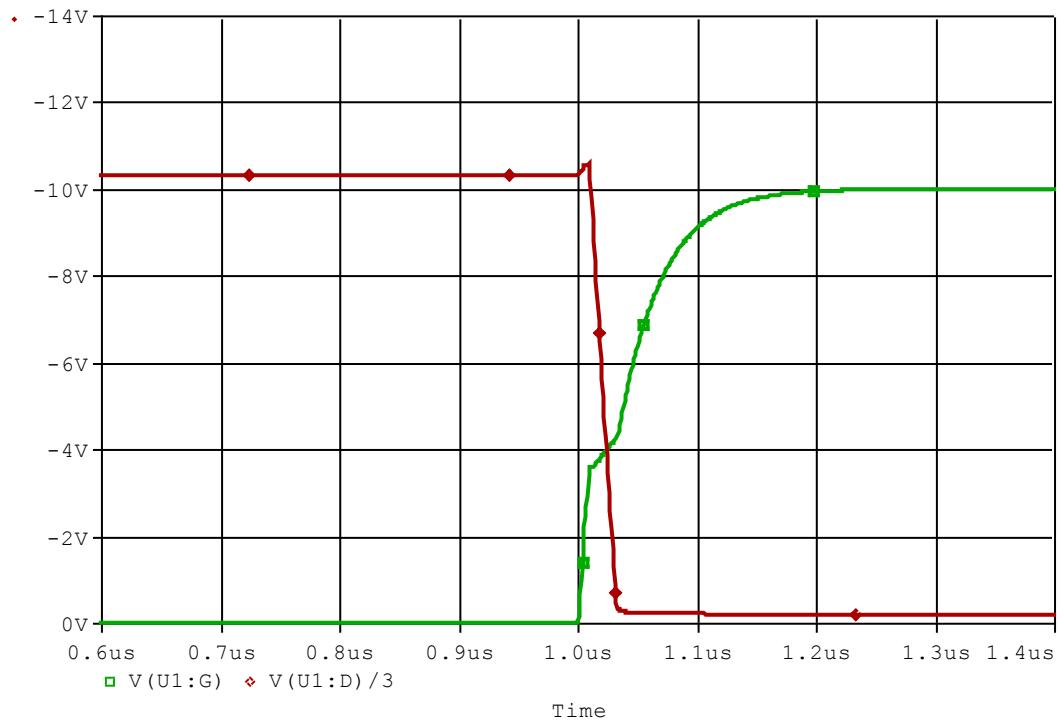


### Simulation Result

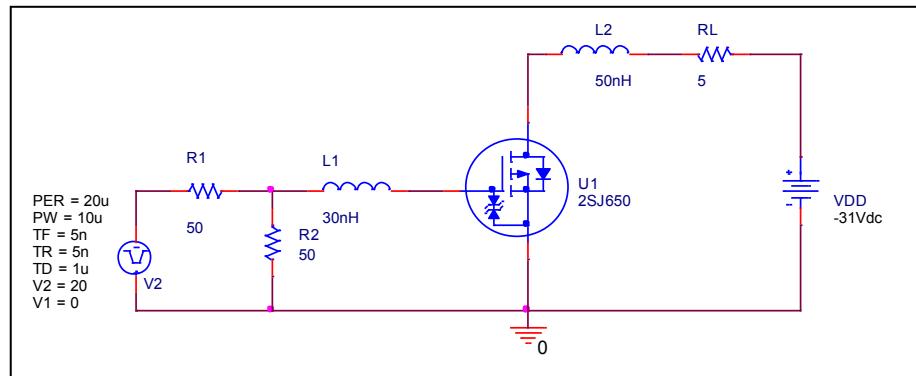
$V_{SD}$ (V)	Cbd(pF)		Error(%)
	Measurement	Simulation	
0	190.000	190.000	0.000
5	75.000	75.940	1.253
10	54.000	53.680	-0.593
15	43.000	43.153	0.356
20	37.000	36.783	-0.586
25	32.000	32.429	1.341
30	29.000	29.224	0.772

## **Switching Time Characteristic**

## Circuit Simulation result



## Evaluation circuit

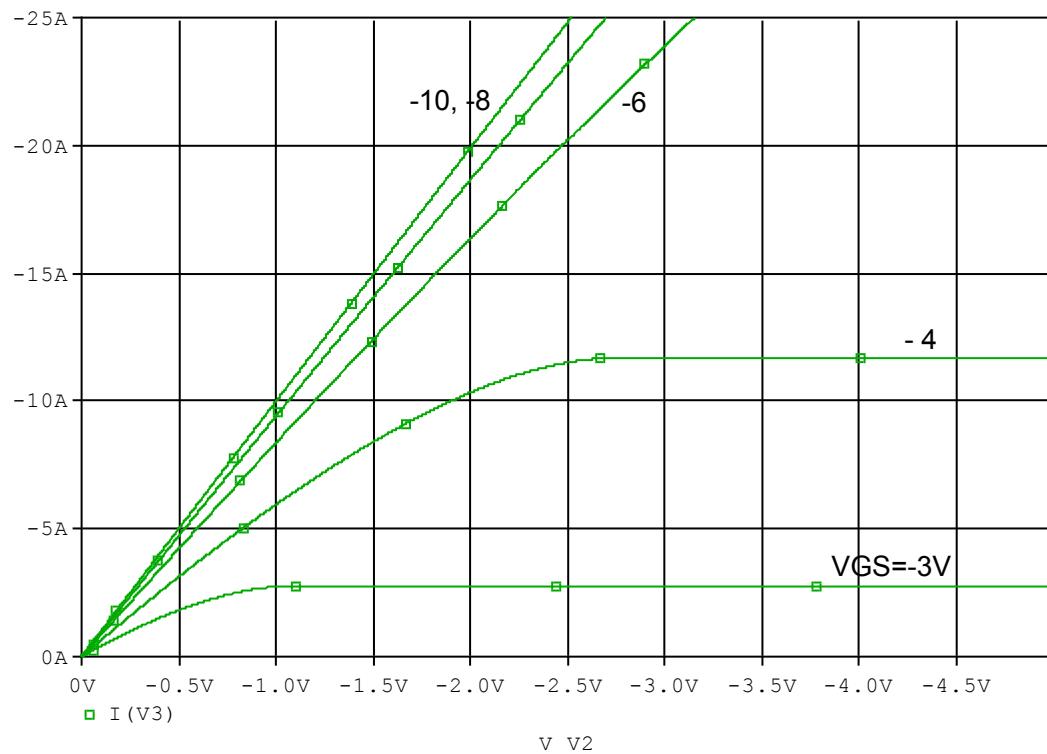


## Simulation Result

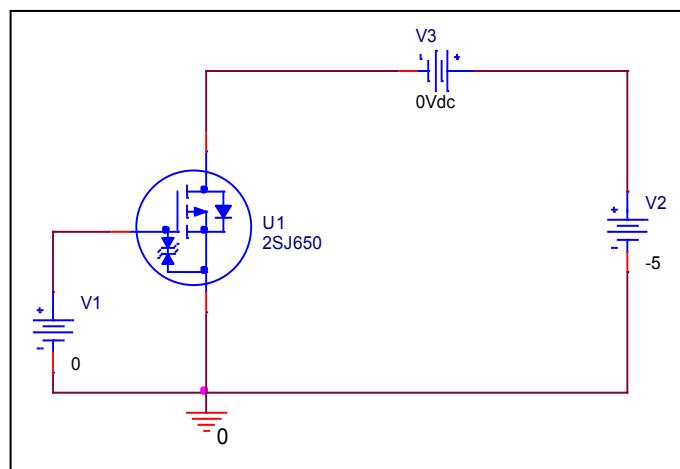
$I_D = -6A$ , $V_{DD} = -30V$ $V_{GS} = 0/-10V$		Measurement	Simulation	Error(%)
td(on)	ns	10.000	10.012	0.12

## Output Characteristic

Circuit Simulation result



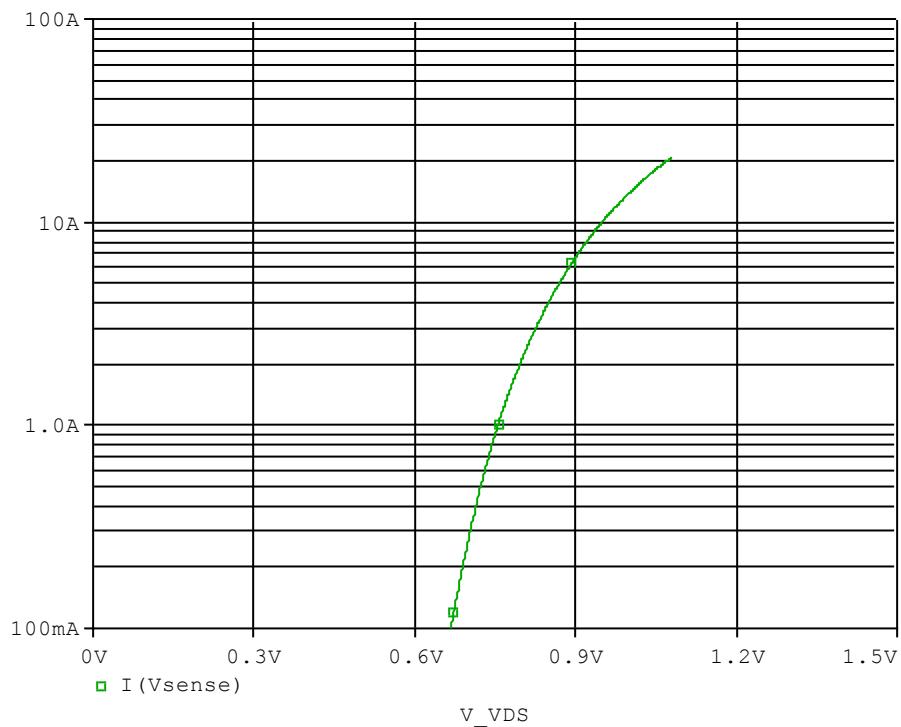
Evaluation circuit



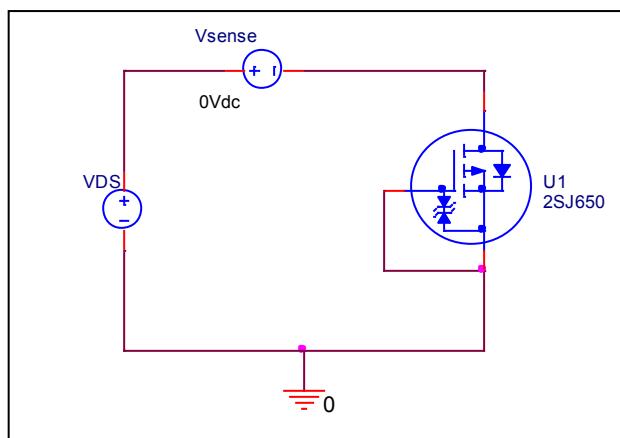
## BODY DIODE SPICE MODEL

### Forward Current Characteristic

## Circuit Simulation Result

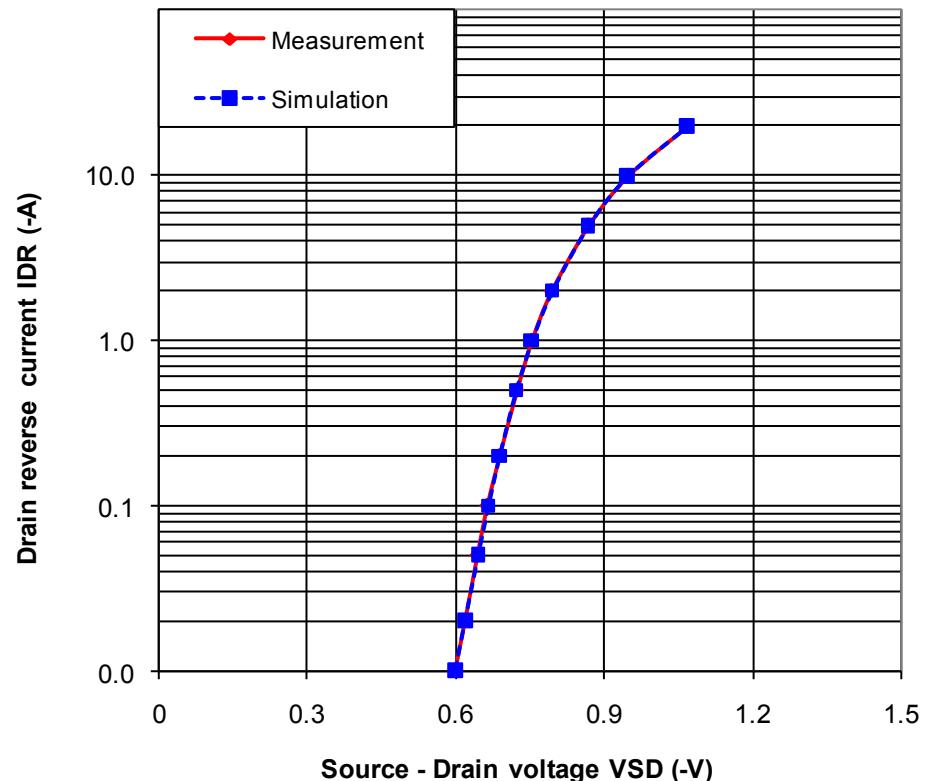


## Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

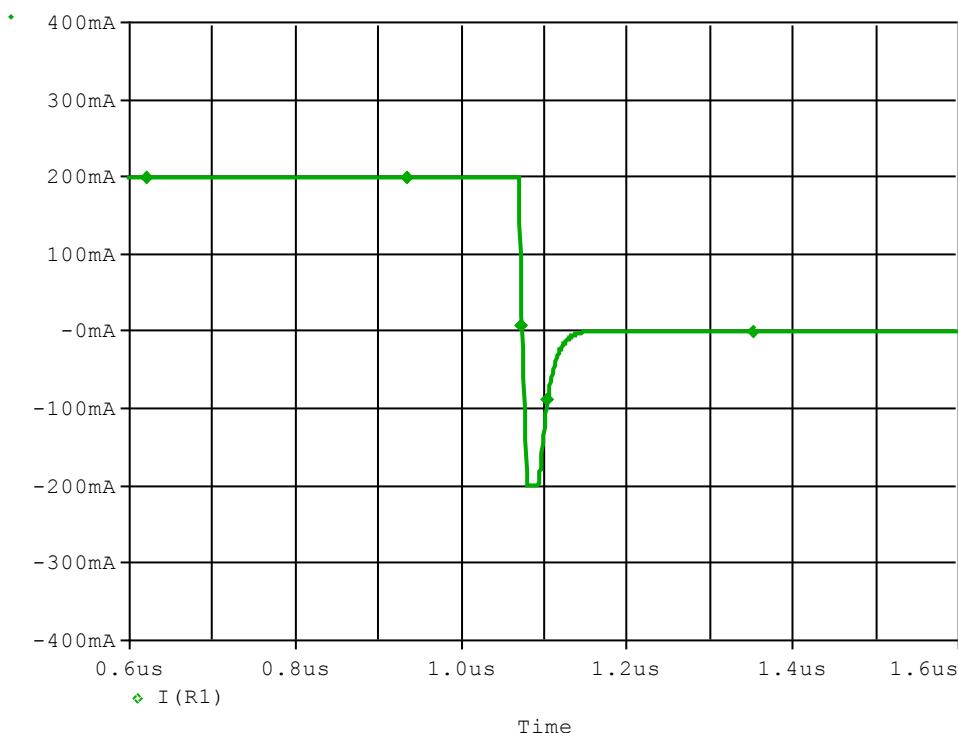


Simulation Result

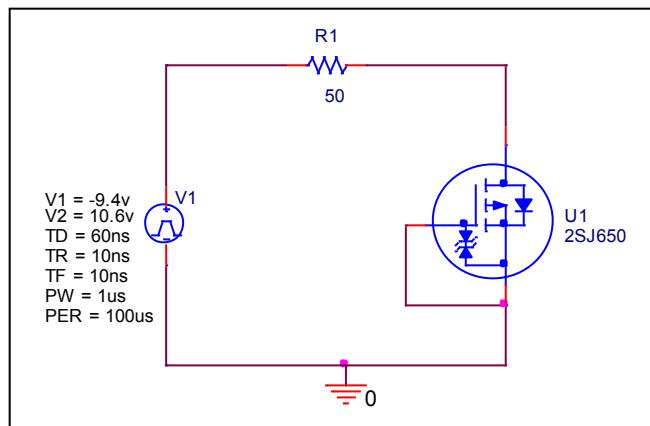
IDR(-A)	VSD(-V)		%Error
	Measurement	Simulation	
0.01	0.6000	0.5994	-0.10
0.02	0.6200	0.6193	-0.11
0.05	0.6450	0.6461	0.17
0.1	0.6650	0.6670	0.31
0.2	0.6900	0.6893	-0.10
0.5	0.7250	0.7231	-0.26
1	0.7550	0.7551	0.02
2	0.7950	0.7962	0.15
5	0.8700	0.8698	-0.02
10	0.9500	0.9494	-0.06
20	1.0700	1.0703	0.03

## Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

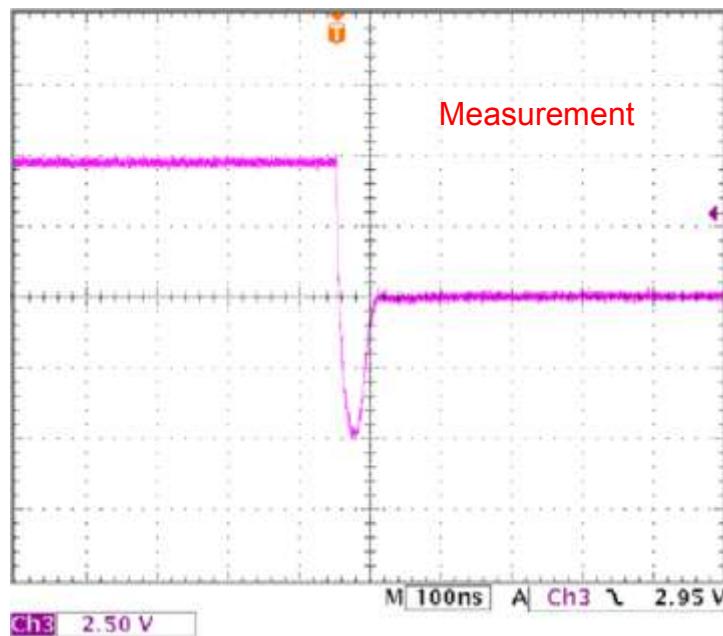


Compare Measurement vs. Simulation

		Measurement	Simulation	Error (%)
trj	ns	18.000	18.402	2.23

## Reverse Recovery Characteristic

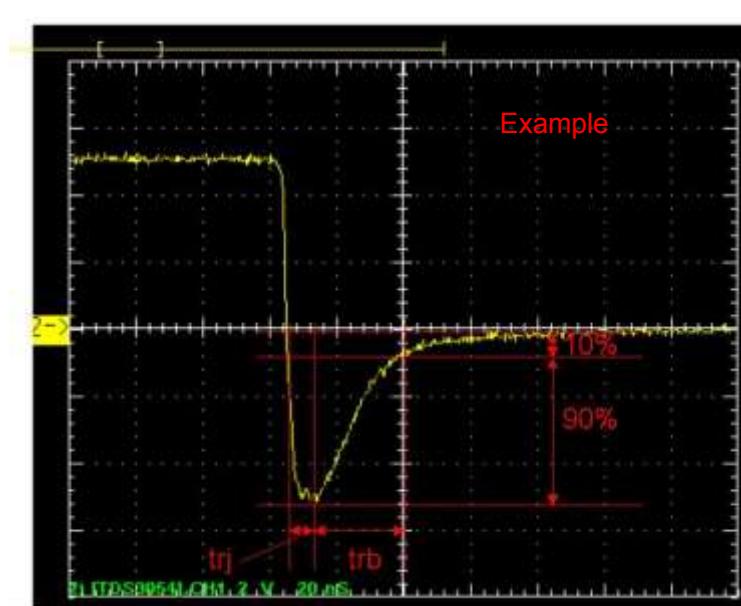
## Reference



$Trj=18.00(\text{ns})$

$Trb=24.00(\text{ns})$

Conditions:  $I_{fwd}=I_{rev}=0.2(\text{A})$ ,  $R_L=50$

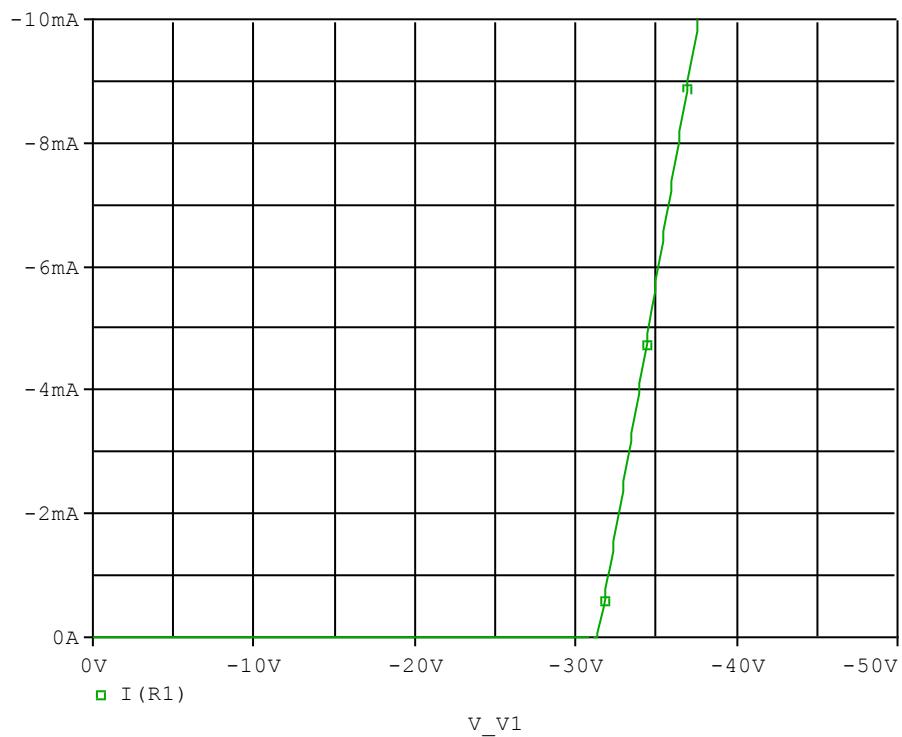


Relation between  $trj$  and  $trb$

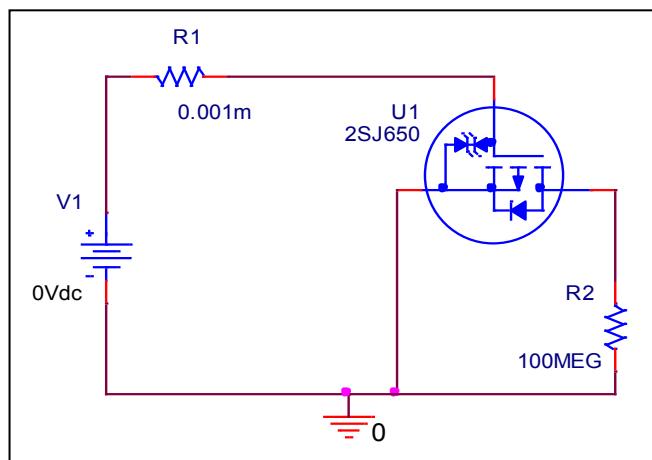
## ESD PROTECTION DIODE SPICE MODEL

### Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



## Zener Voltage Characteristic

## Reference

